## Functional Safety Information TPS61379-Q1 Functional Safety FIT Rate, FMD and Pin FMA

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### 1 Overview

This document contains information for TPS61379-Q1 (VQFN package) to aid in a functional safety system design. Information provided are:

- Functional Safety Failure In Time (FIT) rates of the semiconductor component estimated by the application of industry reliability standards
- Component failure modes and their distribution (FMD) based on the primary function of the device
- Pin failure mode analysis (Pin FMA)

Figure 1-1 shows the device functional block diagram for reference.

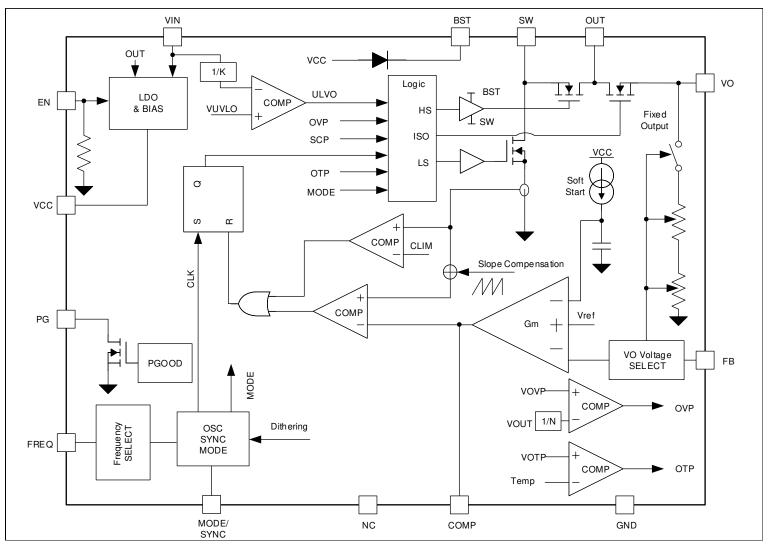


Figure 1-1. Functional Block Diagram

TPS61379-Q1 was developed using a quality-managed development process, but were not developed in accordance with the IEC 61508 or ISO 26262 standards.

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### 2 Functional Safety Failure In Time (FIT) Rates

This section provides Functional Safety Failure In Time (FIT) rates for TPS61379-Q1 based on two different industry-wide used reliability standards:

- Table 2-1 provides FIT rates based on IEC TR 62380 / ISO 26262 part 11
- Table 2-2 provides FIT rates based on the Siemens Norm SN 29500-2

#### Table 2-1. Component Failure Rates per IEC TR 62380 / ISO 26262 Part 11

FIT IEC TR 62380 / ISO 26262	FIT (Failures Per 10 <sup>9</sup> Hours)
Total Component FIT Rate	14
Die FIT Rate	7
Package FIT Rate	7

The failure rate and mission profile information in Table 2-1 comes from the Reliability data handbook IEC TR 62380 / ISO 26262 part 11:

- Mission Profile: Motor Control from Table 11
- Power dissipation: 750 mW
- Climate type: World-wide Table 8
- Package factor (lambda 3): Table 17b
- Substrate Material: FR4
- EOS FIT rate assumed: 0 FIT

#### Table 2-2. Component Failure Rates per Siemens Norm SN 29500-2

Table	Category	Reference FIT Rate	Reference Virtual T <sub>J</sub>
5	CMOS, BICMOS ASICs Analog & Mixed <= 50V supply	25 FIT	55°C

The Reference FIT Rate and Reference Virtual  $T_J$  (junction temperature) in Table 2-2 come from the Siemens Norm SN 29500-2 tables 1 through 5. Failure rates under operating conditions are calculated from the reference failure rate and virtual junction temperature using conversion information in SN 29500-2 section 4.



### 3 Failure Mode Distribution (FMD)

The failure mode distribution estimation for TPS61379-Q1 in Table 3-1 comes from the combination of common failure modes listed in standards such as IEC 61508 and ISO 26262, the ratio of sub-circuit function size and complexity and from best engineering judgment.

The failure modes listed in this section reflect random failure events and do not include failures due to misuse or overstress.

Die Failure Modes	Failure Mode Distribution (%)
VO No output GND or HiZ	50%
VO output not in specification voltage or timing	40%
Load disconnect stuck on	5%
PG false trip, fails to trip	5%

### Table 3-1. Die Failure Modes and Distribution

### 4 Pin Failure Mode Analysis (Pin FMA)

This section provides a Failure Mode Analysis (FMA) for the pins of the TPS61379-Q1. The failure modes covered in this document include the typical pin-by-pin failure scenarios:

- Pin short-circuited to Ground (see Table 4-2)
- Pin open-circuited (see Table 4-3)
- Pin short-circuited to an adjacent pin (see Table 4-4)
- Pin short-circuited to VIN (see Table 4-5)

Table 4-2 through Table 4-5 also indicate how these pin conditions can affect the device as per the failure effects classification in Table 4-1.

Class	Failure Effects		
A	Potential device damage that affects functionality		
В	No device damage, but loss of functionality		
C	No device damage, but performance degradation		
D	No device damage, no impact to functionality or performance		

### Table 4-1. TI Classification of Failure Effects

Figure 4-1 shows the TPS61379-Q1 pin diagram. For a detailed description of the device pins please refer to the *'Pin Configuration and Functions'* section in the TPS61379-Q1 data sheet.

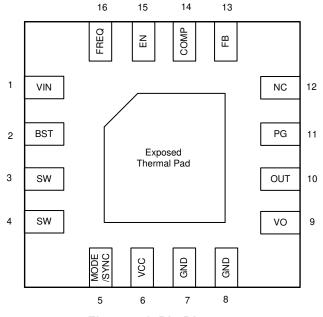


Figure 4-1. Pin Diagram

Following are the assumptions of use and the device configuration assumed for the pin FMA in this section:

- Device used within the *Recommended Operating Conditions* and the *Absolute Maximum Ratings* found in the TPS61379-Q1 data sheet.
- Configuration as shown in the Application and Implementation section found in the TPS61379-Q1 data sheet.

Pin Name	Pin No.	Description of Potential Failure Effects(s)	Failure Effect Class
VIN	1	The device does not operate. Power supply is short.	В
BST	2	Possible device damage	A
SW	3	Potential damage to inductor and pin	A
SW	4	Potential damage to inductor and pin	A
MODE/SYNC	5	The device remains in Auto PFM mode. Loss of forced PWM mode, spread spectrum functionality, and frequency synchronization functionality	С
VCC	6	Output voltage out of regulation	В
GND	7	No effect	D
GND	8	No effect	D
VO	9	The device remains in hiccup output short circuit protection mode.	В
OUT	10	Potential damage to device	A
PG	11	Correct output voltage. Loss of PG functionality	С
NC	12	No effect	D
FB	13	Output voltage is regulated to 5 V.	В
COMP	14	No output voltage	В
EN	15	Loss of ENABLE functionality. The device remains in Shut Down mode.	В
FREQ	16	Switching frequency is 2 MHz typically.	С

#### Table 4-2. Pin FMA for Device Pins Short-Circuited to Ground

### Table 4-3. Pin FMA for Device Pins Open-Circuited

Pin Name	Pin No.	Description of Potential Failure Effects(s)	
VIN	1	The device does not work. Output voltage is 0 V.	В
BST	2	The device is damaged.	A
SW	3	Possible device damage	Α
SW	4	Possible device damage	Α
MODE/SYNC	5	Device remains in auto PFM mode. Loss of Forced PWM mode, spread spectrum functionality, and frequency synchronization functionality	С
VCC	6	High ripple on VCC pin. Efficiency is lower.	С
GND	7	Possible device damage	Α
GND	8	Possible device damage	A
VO	9	No output voltage	В
OUT	10	Possible device damage	Α
PG	11	Correct output voltage. Loss of PG functionality	С
NC	12	No effect	D
FB	13	Output voltage is out of regulation.	В
COMP	14	Output voltage is out of regulation.	В
EN	15	Loss of ENABLE functionality. The device remains in Shut Down mode.	В
FREQ	16	No output voltage	В

#### Table 4-4. Pin FMA for Device Pins Short-Circuited to Adjacent Pin

Pin Name	Pin No.	Shorted to	Description of Potential Failure Effects(s)	Failure Effect Class
VIN	1	BST	Possible device damage	А
BST	2	SW	Output voltage out of regulation	В
SW	3	SW	No effect	D
SW	4	MODE/SYNC	Possible device damage	A



Pin Name	Pin No.	Shorted to	Description of Potential Failure Effects(s)	Failure Effect Class
MODE/SYNC	5	VCC	The device remains in forced PWM mode. Loss of Auto PFM mode and frequency synchronization functionality	С
VCC	6	GND	The device does not work. V <sub>OUT</sub> = 0 V	В
GND	7	GND	No effect	D
GND	8	VO	The device remains in hiccup output short circuit protection mode.	В
VO	9	OUT	Loss of Down mode functionality and hiccup output short circuit protection	В
OUT	10	PG	Possible device damage	A
PG	11	NC	Potential device damage if PG is pulled up to higher than 6 V.	A
NC	12	FB	No effect	D
FB	13	COMP	No output voltage	В
COMP	14	EN	OVP is triggered	В
EN	15	FREQ	No output voltage	В
FREQ	16	VIN	The FREQ pin is damaged if supply voltage is higher than 6 V.	А

### Table 4-4. Pin FMA for Device Pins Short-Circuited to Adjacent Pin (continued)

### Table 4-5. Pin FMA for Device Pins Short-Circuited to VIN

Pin Name	Pin No.	Description of Potential Failure Effects(s)	Failure Effect Class
VIN	1	No effect	D
BST	2	Possible device damage	A
SW	3	Damage to internal power FETs	A
SW	4	Damage to internal power FETs	A
MODE/SYNC	5	The MODE/SYNC pin damaged if supply voltage is higher than 6 V.	A
VCC	6	VCC pin is damaged if supply voltage is higher than 6 V.	A
GND	7	Possible device damage due to large current	A
GND	8	Possible device damage due to large current	A
VO	9	VO = VIN	В
OUT	10	The device remains in Hiccup mode. No output voltage	В
PG	11	Possible device damage	A
NC	12	The NC pin is damaged if supply voltage is higher than 6 V.	A
FB	13	The FB pin is damaged if supply voltage is higher than 6 V.	A
COMP	14	The COMP pin is damaged if supply voltage is higher than 6 V.	A
EN	15	The EN pin is damaged if supply voltage is higher than 6 V.	A
FREQ	16	The FREQ pin is damaged if supply voltage is higher than 6 V.	A

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